## ABSTRACT OF THE DISCLOSURE

A computer implemented method for development profile simulation in accordance with an embodiment of the present invention includes calculating optical intensities in 5 photosensitive resist, calculating a spatial average value of the optical intensities, reading a measured changing ratio of a dissolution rate of the photosensitive resist relating to an alkaline concentration changed by at least one of exposure dose on the photosensitive resist, a position in the thickness direction of the photosensitive resist and an alkaline 10 concentration of developer for the photosensitive resist, obtaining a calculated dissolution rate by using the spatial ...average value and the measured changing ratio, and predicting a pattern shape of the photosensitive resist from the 15 calculated dissolution rate.

## BEST AVAILABLE COPY